

Rectifier diodes ultrafast, rugged

BYW29EX series

GENERAL DESCRIPTION

Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

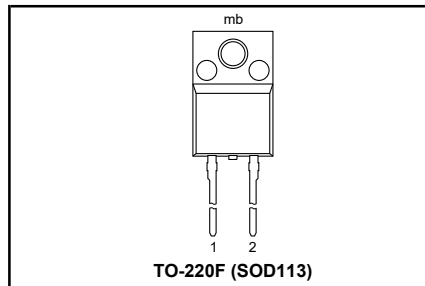
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V_{RRM}	BYW29EX- Repetitive peak reverse voltage	150 150	200 200	V
V_F	Forward voltage	0.895	0.895	V
$I_{F(AV)}$	Forward current	8	8	A
t_{rr}	Reverse recovery time	25	25	ns
I_{RRM}	Repetitive peak reverse current	0.2	0.2	A

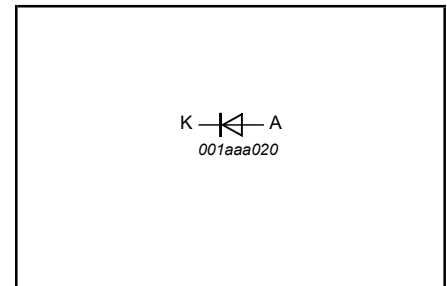
PINNING - SOD113

PIN	DESCRIPTION
1	cathode
2	anode
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RRM}	Repetitive peak reverse voltage		-	-150 150	-200 200	V
V_{RWM}	Crest working reverse voltage		-	150	200	V
V_R	Continuous reverse voltage		-	150	200	V
$I_{F(AV)}$	Average forward current ¹	square wave; $\delta = 0.5$; $T_{hs} \leq 106^\circ\text{C}$ sinusoidal; $a = 1.57$; $T_{hs} \leq 109^\circ\text{C}$	-	8		A
$I_{F(RMS)}$	RMS forward current		-	7.3		A
I_{FRM}	Repetitive peak forward current	$t = 25\ \mu\text{s}$; $\delta = 0.5$; $T_{hs} \leq 106^\circ\text{C}$	-	11.3		A
I_{FSM}	Non-repetitive peak forward current	$t = 10\ \text{ms}$ $t = 8.3\ \text{ms}$ sinusoidal; with reapplied	-	80		A
I_{FSM}^2	I^2t for fusing	$V_{RWM(max)}$ $t = 10\ \text{ms}$	-	32		A ² s
I_{RRM}	Repetitive peak reverse current	$t_p = 2\ \mu\text{s}$; $\delta = 0.001$	-	0.2		A
I_{RSM}	Non-repetitive peak reverse current	$t_p = 100\ \mu\text{s}$	-	0.2		A
T_{stg}	Storage temperature		-40	150		°C
T_j	Operating junction temperature		-	150		°C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_C	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC

$T_{hs} = 25 \text{ }^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	R.M.S. isolation voltage from both terminals to external heatsink	$f = 50\text{-}60 \text{ Hz}$; sinusoidal waveform; $R.H. \leq 65\%$; clean and dustfree	-		2500	V
C_{isol}	Capacitance from both terminals to external heatsink	$f = 1 \text{ MHz}$	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j\text{-}hs}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	5.5	K/W
$R_{th\ j\text{-}a}$	Thermal resistance junction to ambient	without heatsink compound in free air	-	55	7.2	K/W
			-		-	K/W

STATIC CHARACTERISTICS

$T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 8 \text{ A}$; $T_j = 150 \text{ }^\circ\text{C}$	-	0.80	0.895	V
		$I_F = 8 \text{ A}$	-	0.92	1.05	V
		$I_F = 20 \text{ A}$	-	1.1	1.3	V
I_R	Reverse current	$V_R = V_{RWM}$; $T_j = 100 \text{ }^\circ\text{C}$	-	0.2	0.6	mA
		$V_R = V_{RWM}$	-	2	10	μA

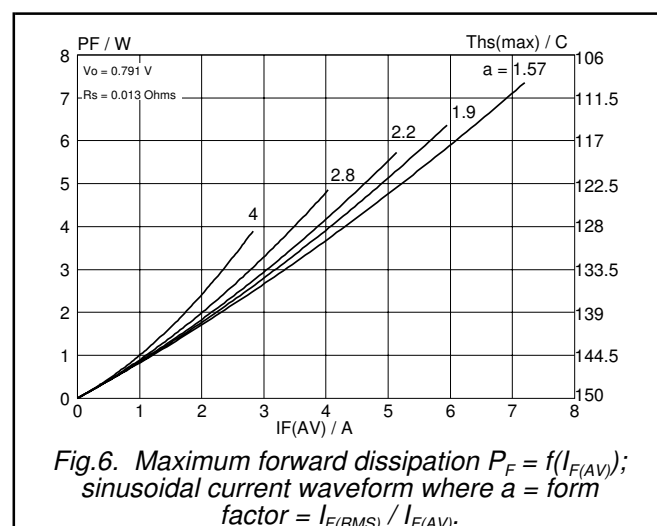
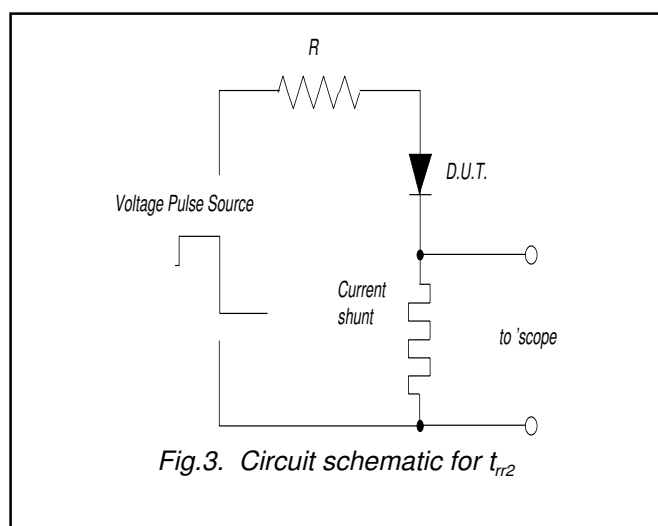
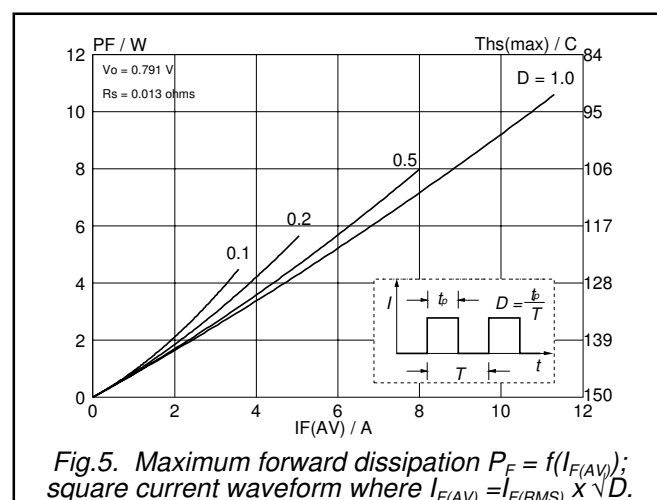
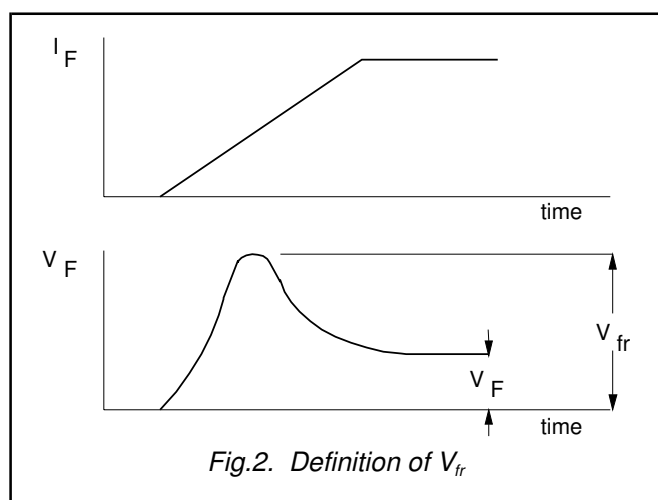
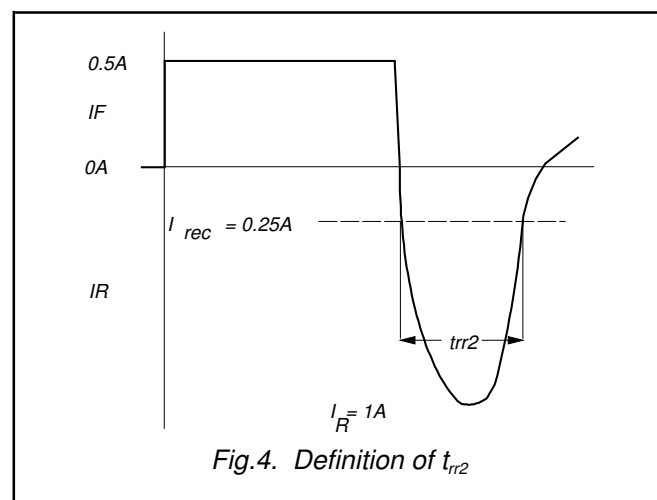
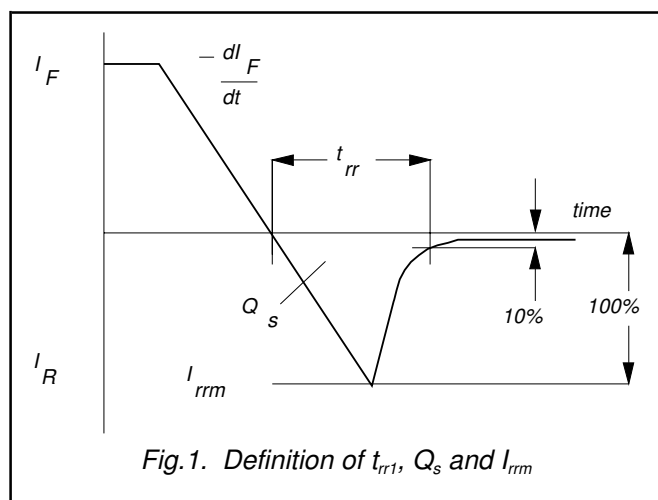
DYNAMIC CHARACTERISTICS

$T_j = 25 \text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge	$I_F = 2 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 20 \text{ A}/\mu\text{s}$	-	4	11	nC
t_{rr1}	Reverse recovery time	$I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	25	ns
t_{rr2}	Reverse recovery time	$I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; $I_{rec} = 0.25 \text{ A}$	-	15	20	ns
V_{fr}	Forward recovery voltage	$I_F = 1 \text{ A}$; $di_F/dt = 10 \text{ A}/\mu\text{s}$	-	1	-	V

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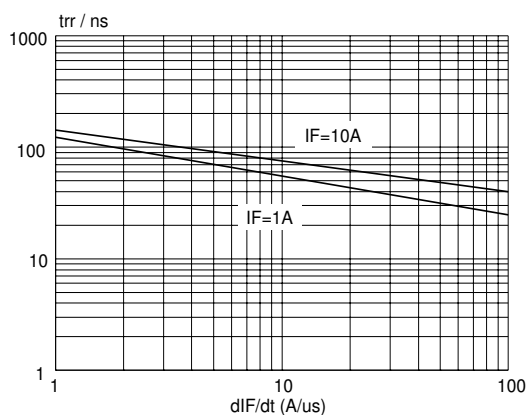


Fig.7. Maximum t_{rr} at $T_j = 25\text{ }^{\circ}\text{C}$.

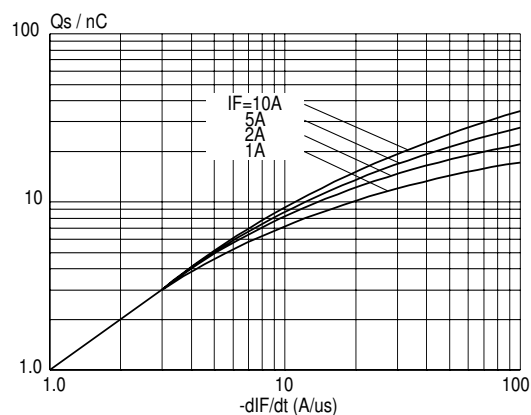


Fig.10. Maximum Q_s at $T_j = 25\text{ }^{\circ}\text{C}$.

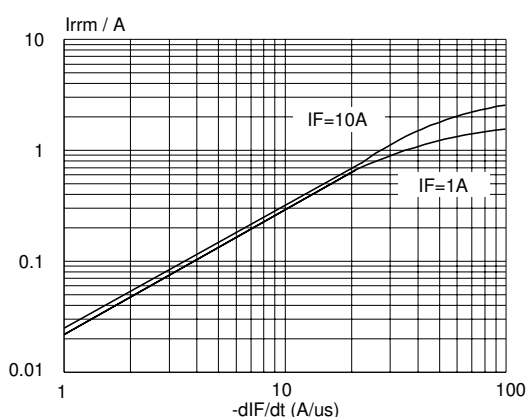


Fig.8. Maximum I_{rrm} at $T_j = 25\text{ }^{\circ}\text{C}$.

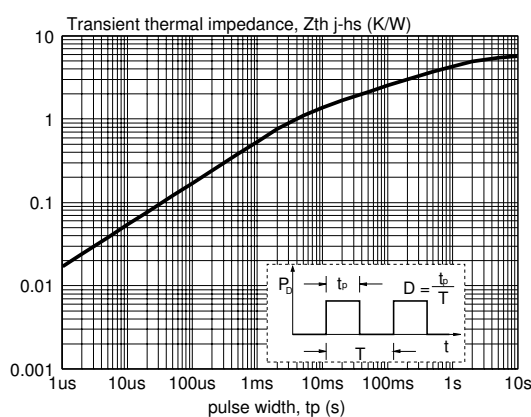


Fig.11. Transient thermal impedance; $Z_{th\ j-hs} = f(t_p)$.

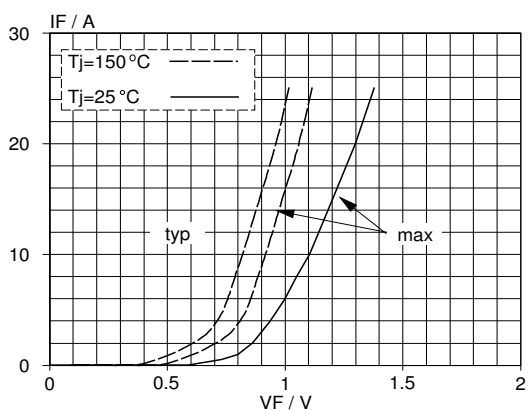


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

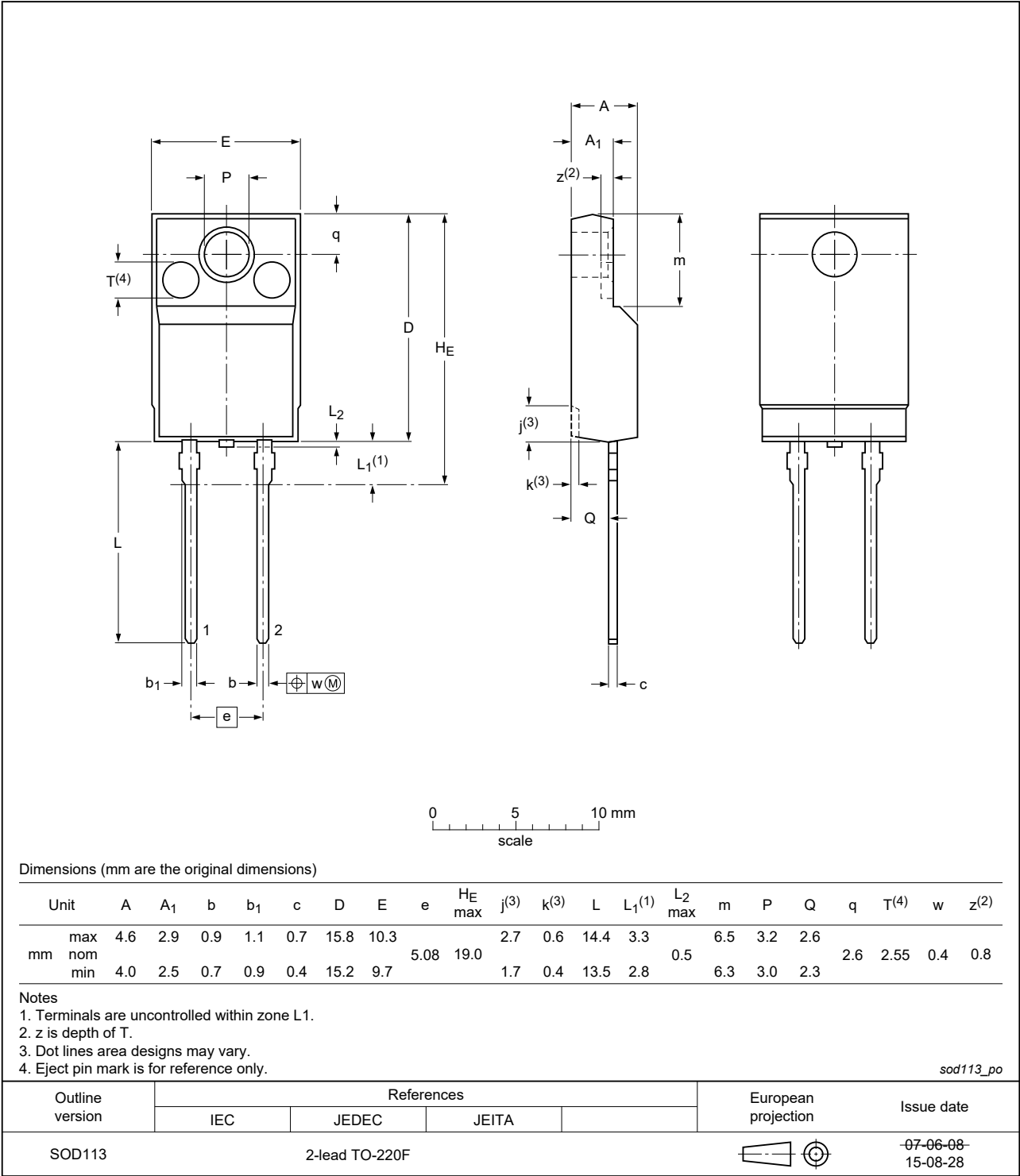
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MECHANICAL DATA

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 2-lead TO-220 'full pack'

SOD113



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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